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## JAYPEE UNIVERSITY OF INFORMATION TECHNOLOGY, WAKNAGHAT TEST-2 EXAMINATION- APRIL -2018

B. Tech (II<sup>nd</sup> Semester) (ECE/CSE/IT)

COURSE CODE: 10B11EC211

MAX. MARKS: 25

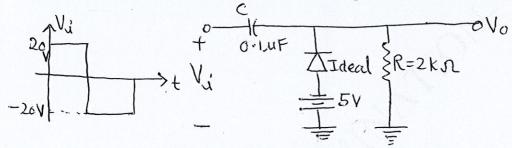
**COURSE CREDITS: 04** 

MAX. TIME:1.5 HR

Note: All questions are compulsory. Carrying of mobile phone during examination will be treated as case of unfair means. Marks are indicated below each question

1. (a) In p-type semiconductor materials holes are in majority, whereas in n-type semiconductor materials electrons are in majority. Explain the reason with suitable diagram.

(b) Explain the working of the following circuit and draw the output waveform. [3]



(c) For the following circuit, determine the value of  $I_Z$  and  $V_L$  for (i)  $R_L = 1.2 \text{ K}\Omega$  (ii)  $R_L = 3 \text{ K}\Omega$ .

$$V_{3} = V_{2} = 10 \text{ V}$$

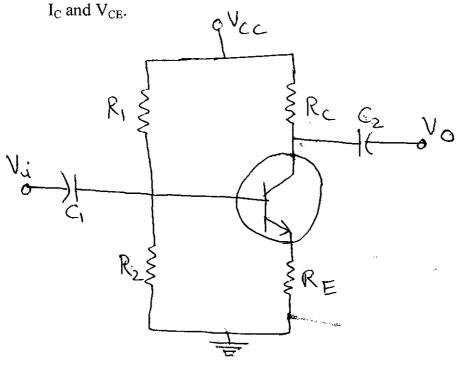
$$V_{2} = 10 \text{ V}$$

$$V_{2} = 30 \text{ mW}$$

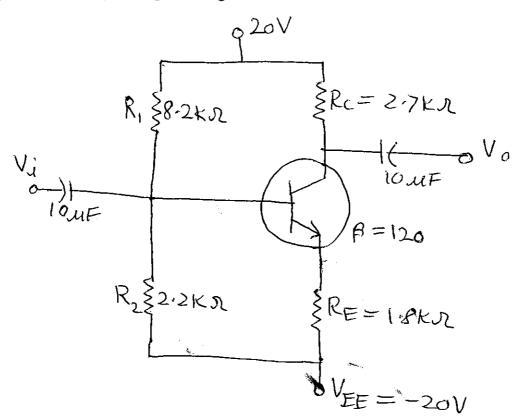
- 2 (a) Draw and explain the construction and working of pnp transistor in active mode. [3]
  - (b) Draw the circuit diagram for common emitter, common base and common collector configuration, indicating input and output voltages and currents. [3]
  - (c) Draw the input and output characteristic of common emitter configuration and show the saturation, active and cut-off region on the graph. [2]

[4]

3 (a) For the given circuit, draw the dc equivalent circuit and derive the expression for  $I_{\text{B}}$ ,



(b) Determine  $V_{\text{C}}$  and  $V_{\text{B}}$  for the given network:



[4]